

FORM PTO-120
(Rev. 12-29-99)

U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE

ATTORNEY'S DOCKET NUMBER

TRANSMITTAL LETTER TO THE UNITED STATES
DESIGNATED/ELECTED OFFICE (DO/EO/US)
CONCERNING A FILING UNDER 35 U.S.C. 371FILED: FEBRUARY 13, 2001
566.39636X00

U.S. APPLICATION NO. 09/762823 (37 CFR 1.5)

09/762823

INTERNATIONAL APPLICATION NO.

INTERNATIONAL FILING DATE

PRIORITY DATE CLAIMED

PCT/JP98/03609

13 August 1998 (13.08.98)

TITLE OF INVENTION: ADHESIVE FOR BONDING CIRCUIT MEMBERS, CIRCUIT BOARD AND
PROCESS FOR ITS PRODUCTIONAPPLICANT(S) FOR DO/EO/US: Itsuo WATANABE, Akira NAGAI, Kazuhiro ISAKA, Osamu WATANABE,
Kazuyoshi KOJIMA

Applicant herewith submits to the United States Designated/Elected Office (DO/EO/US) the following items and other information:

1. ☒ This is a **FIRST** submission of items concerning a filing under 35 U.S.C. 371.
2. ☐ This is a **SECOND** or **SUBSEQUENT** submission of items concerning a filing under 35 U.S.C. 371.
3. ☐ This express request to begin national examination procedures (35 U.S.C. 371(f)) at any time rather than delay examination until the expiration of the applicable time limit set in 35 U.S.C. 371(b) and PCT Articles 22 and 39(1).
4. ☒ A proper Demand for International Preliminary Examination was made by the 19th month from the earliest claimed priority date.
5. ☒ A copy of the International Application as filed (35 U.S.C. 371(c)(2))
 - a. ☐ is transmitted herewith (required only if not transmitted by the International Bureau).
 - b. ☒ has been transmitted by the International Bureau.
 - c. ☐ is not required, as the application was filed in the United States Receiving Office (RO/US).
6. ☒ A translation of the International Application into English (35 U.S.C. 371(c)(2)).
7. ☐ Amendments to the claims of the International Application under PCT Article 19 (35 U.S.C. 371(c)(3))
 - a. ☐ are transmitted herewith (required only if not transmitted by the International Bureau).
 - b. ☐ have been transmitted by the International Bureau.
 - c. ☐ have not been made; however, the time limit for making such amendments has NOT expired.
 - d. ☐ have not been made and will not be made.
8. ☐ A translation of the amendments to the claims under PCT Article 19 (35 U.S.C. 371(c)(3)).
9. ☐ An oath or declaration of the inventor(s) (35 U.S.C. 371(c)(4)).
10. ☐ A translation of the annexes to the International Preliminary Examination Report under PCT Article 36 (35 U.S.C. 371(c)(5)).

Items 11. to 16. below concern document(s) or information included:

11. ☐ An Information Disclosure Statement under 37 CFR 1.97 and 1.98.
12. ☐ An assignment document for recording. A separate cover sheet in compliance with 37 CFR 3.28 and 3.31 is included.
13. ☒ A FIRST preliminary amendment.
☐ A SECOND or SUBSEQUENT preliminary amendment.
14. ☐ A substitute specification.
15. ☒ A change of power of attorney and/or address letter.
16. ☒ Other items or information:

INTERNATIONAL PUBLICATION COVER SHEET NO. WO00/09623
INTERNATION SEARCH REPORT W/REFS. THEREOF
FIGS. 1-2CREDIT CARD PAYMENT FORM
TRANSLATION OF AMENDMENT UNDER ART. 34

17. ☒ The following fees are submitted:**BASIC NATIONAL FEE (37 CFR 1.492(a)(1)-(5)):**

Neither international preliminary examination fee (37 CFR 1.482)
nor international search fee (37 CFR 1.445(a)(2)) paid to USPTO
and International Search Report not prepared by the EPO or JPO \$970.00

International preliminary examination fee (37 CFR 1.482) not paid to
USPTO but International Search Report prepared by the EPO or JPO \$840.00

International preliminary examination fee (37 CFR 1.482) not paid to USPTO but
international search fee (37 CFR 1.445(a)(2)) paid to USPTO \$690.00

International preliminary examination fee paid to USPTO (37 CFR 1.482)
but all claims did not satisfy provisions of PCT Article 33(1)-(4) \$670.00

International preliminary examination fee paid to USPTO (37 CFR 1.482)
and all claims satisfied provisions of PCT Article 33(1)-(4) \$96.00

ENTER APPROPRIATE BASIC FEE AMOUNT =**CALCULATIONS** PTO USE ONLY

Surcharge of \$130.00 for furnishing the oath or declaration later than ☐ 20 ☐ 30
months from the earliest claimed priority date (37 CFR 1.492(e)).

\$

860.00

CLAIMS	NUMBER FILED	NUMBER EXTRA	RATE	
Total claims	31 - 20 =	11	X \$18.00	\$ 198.00
Independent claims	5 - 3 =	2	X \$78.00	\$ 160.00
MULTIPLE DEPENDENT CLAIM(S) (if applicable)			+ \$260.00	\$ 0.00

TOTAL OF ABOVE CALCULATIONS = \$ 1,218.00

Reduction of 1/2 for filing by small entity, if applicable. A Small Entity Statement
must also be filed (Note 37 CFR 1.9, 1.27, 1.28).

\$

0.00

SUBTOTAL = \$ 1,218.00

Processing fee of \$130.00 for furnishing the English translation later than ☐ 20 ☐ 30
months from the earliest claimed priority date (37 CFR 1.492(f)).

\$

0.00

TOTAL NATIONAL FEE = \$ 1,218.00

Fee for recording the enclosed assignment (37 CFR 1.21(h)). The assignment must be
accompanied by an appropriate cover sheet (37 CFR 3.28, 3.31). \$40.00 per property +

\$

0.00

TOTAL FEES ENCLOSED = \$ 1,218.00

Amount to be

refunded:

\$

charged:

\$

card payment form

a. ☒ A check in the amount of \$ 1,218.00 to cover the above fees is enclosed.

b. ☐ Please charge my Deposit Account No. _____ in the amount of \$ _____ to cover the above fees.
A duplicate copy of this sheet is enclosed.

c. ☒ The Commissioner is hereby authorized to charge any additional fees which may be required, or credit any
overpayment to Deposit Account No. 01-2135. A duplicate copy of this sheet is enclosed.

NOTE: Where an appropriate time limit under 37 CFR 1.494 or 1.495 has not been met, a petition to revive (37 CFR 1.137(a) or (b)) must be filed and granted to restore the application to pending status.

SEND ALL CORRESPONDENCE TO

William I. Solomon
Antonelli, Terry, Stout & Kraus, LLP
1300 n. 17th Street
Suite 1800
Arlington, VA 22209

SIGNATURE:

William I. Solomon

NAME

28,565

REGISTRATION NUMBER

566.39636X00

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant(s): WATANABE, et al.

Filed: February 13, 2001

For: ADHESIVE FOR BONDING CIRCUIT MEMBERS, CIRCUIT
BOARD AND PROCESS FOR ITS PRODUCTION

PRELIMINARY AMENDMENT

Assistant Commissioner for Patents
Washington, D.C. 20231

February 13, 2001

Sir:

Please amend the above-identified application, prior to
calculation of the filing fee and prior to examination, as
follows:

IN THE CLAIMS

Please amend the claims as follows:

Claim 1, line 7, insert --insulative-- before
"inorganic";
line 8, insert --insulative-- before
"inorganic".

Claim 2, line 9, insert --insulative-- before
"inorganic";
line 10, insert --insulative-- before
"inorganic".

Claim 3, line 9, insert --insulative-- before
"inorganic";

09762823 002201

line 10, insert --insulative-- before
"inorganic".

Claim 4, line 7, insert --insulative-- before
"inorganic".

Claim 7, line 2, delete "first" and insert --third--;
line 4, delete "second" and insert --fourth--.

Claim 13, line 2, delete "any one of claims 7, 9 or 11"
and insert --claim 7--;
line 6, insert --insulative-- before
"inorganic".

Claim 14, line 2, delete "any one of claims 1, 2, 3, 4 or
13" and insert --claim 1--;
line 3, insert --insulative-- before
"inorganic".

Claim 15, line 2, delete "any one of claims" and insert
--claim--, same line 2, delete "to 14".

Claim 16, line 2, delete "any one of claims 1, 2, 3, 4,
13 or 14" and insert --claim 1--;
line 5, insert --insulative-- before
"inorganic".

Claim 17, line 2, delete "any one of claims 1 to 16" and

insert --claim 1--.

Claim 18, line 2, delete "any one of claims 1 to 17" and
insert --claim 1--.

Claim 19, line 2, delete "any one of claims 1 to 18" and
insert --claim 1--.

Claim 21, line 2, delete "any one of claims 1 to 20" and
insert --claim 1--.

Claim 22, line 15, delete "any one of claims 1 to 21" and
insert --claim 1--.

Please cancel claims 23-25 without prejudice or
disclaimer.

Claim 26, line 12, delete "or 3".

Claim 27, line 11, delete "any one";
line 12, delete "of claims 7 to 13" and insert
--claim 7--.

Please add the following new claims to the application:

--28. A circuit board comprising:
a first circuit member, which is an inorganic
insulating substrate, having a first connecting terminal; and

a second circuit member, which is an organic insulating substrate, having a second connecting terminal;

said first connecting terminal and the second connecting terminal being disposed facing each other, and an adhesive being put between the first connecting terminal and the second connecting terminal which are disposed facing each other; and

said first connecting terminal and the second connecting terminal disposed facing each other being electrically interconnected by pressing;

said adhesive being the adhesive for bonding circuit members according to claim 2; and

at least any of the first adhesive layer stands adhered on the side of said first circuit member.

29. The circuit board according to claim 28, wherein the first circuit member is a semiconductor chip.

30. A circuit board comprising:

a first circuit member, which is an inorganic circuit member, having a first connecting terminal; and

a second circuit member, which is an organic circuit member, having a second connecting terminal;

said first connecting terminal and the second connecting terminal being disposed facing each other, and an adhesive being put between the first connecting terminal and the second connecting terminal which are disposed facing each other; and

Account No. 01-2135 (Case No. 566.39636X00) and please credit
any excess fees to such Deposit Account.

Respectfully submitted,

ANTONELLI, TERRY, STOUT & KRAUS, LLP



William I. Solomon
Registration No. 28,565

1300 North Seventeenth Street
Suite 1800
Arlington, VA 22209
Tel.: 703-312-6600
Fax.: 703-312-6666

WIS/slk

11 PRTS

JC02 Rec'd PCT/PTO 13 FEB 2001

HC1412

SPECIFICATION

ADHESIVE FOR BONDING CIRCUIT MEMBERS,

CIRCUIT BOARD

5

AND

PROCESS FOR ITS PRODUCTION

TECHNICAL FIELD

10 This invention relates to an adhesive for bonding
circuit members which is used to bond and fix a semiconductor
chip to a substrate by, e.g., flip-chip mounting and also
to electrically interconnect electrodes of the both. It
also relates to a circuit board having circuit members
bonded to one another, and a process for producing the
15 circuit board.

BACKGROUND ART

20 In the field of semiconductor mounting, flip-chip
mounting by which IC (integrated circuits) are directly
mounted on a printed substrate or a flexible wiring board
attracts notice as a new mounting form adaptable to
achievement of lower cost and higher precision.

25 As methods for such flip-chip mounting, known are a
method in which solder bumps are provided at terminals of
a chip to effect solder bonding and a method in which
electrical interconnection is made via a conductive

adhesive. These methods have a problem that a stress due to a difference in coefficient of thermal expansion between the chip and the substrate that are to be bonded to each other may be generated to lower connection reliability when products are exposed to environment of various types.

Accordingly, a method has come to be commonly studied in which an underfill material of an epoxy resin type is injected into a chip-/substrate gap in order to relax the stress at the bonding interface.

There, however, is another problem that the step of injecting such an underfill makes a process complicate to bring about a disadvantage in view of productivity and cost.

To solve such a problem, what recently attracts notice from the viewpoint of process simplicity is flip-chip mounting that makes use of an anisotropic conductive adhesive having both anisotropic conductivity and encapsulation function.

However, where a chip is directly mounted on a substrate via the anisotropic conductive adhesive, the stress due to a difference in coefficient of thermal expansion between the chip and the substrate may be generated in a temperature cycle test. This brings about a problem that the adhesive may cause an increase in connection resistance or separation at adhesive layers when reliability tests such as a thermal shock test, a PCT (pressure cooker test) and a solder bath immersion test are made. Also, where projected electrodes are formed at connecting terminals of a chip, there is a

problem that the stress due to a difference in coefficient of thermal expansion between the chip and the substrate may concentrate at the interface between the projected electrodes and the chip in the reliability tests, making
5 the projected electrodes separate from their interface with chip electrodes to cause faulty conduction.

DISCLOSURE OF THE INVENTION

09762822-002301
The present invention provides an adhesive for bonding
10 circuit members that does hardly cause any increase in connection resistance or separation at adhesive layers to bring about a great improvement in connection reliability, and provides a circuit board having circuit members bonded to one another, and a process for producing the circuit
15 board.

A first adhesive for bonding circuit members according to the present invention is an adhesive for bonding circuit members which is to be put between circuit electrodes facing each other; the circuit electrodes facing each other being
20 pressed interposing the adhesive between them, to interconnect the electrodes electrically in the direction of pressing;

the adhesive comprising an adhesive resin composition and an inorganic filler; the inorganic filler being
25 contained in an amount of from 10 to 200 parts by weight based on 100 parts by weight of the adhesive resin

composition.

A second adhesive for bonding circuit members according to the present invention is an adhesive for bonding circuit members which is to be put between circuit electrodes facing each other; the circuit electrodes facing each other being pressed interposing the adhesive between them, to interconnect the electrodes electrically in the direction of pressing;

the adhesive being in multi-layer constitution having a first adhesive layer comprising an adhesive resin composition and an inorganic filler and containing the inorganic filler in an amount of from 10 to 200 parts by weight based on 100 parts by weight of the adhesive resin composition, and a second adhesive layer containing an adhesive resin composition as a main ingredient.

A third adhesive for bonding circuit members according to the present invention is an adhesive for bonding circuit members which is to be put between circuit electrodes facing each other; the circuit electrodes facing each other being pressed interposing the adhesive between them, to interconnect the electrodes electrically in the direction of pressing;

the adhesive comprising an adhesive resin composition and an inorganic filler and having an average coefficient of thermal expansion of 200 ppm/°C or below at 110 to 130°C after curing. It may preferably have an average coefficient

of thermal expansion of from 30 to 200 ppm/°C at 110 to 130°C after curing.

A fourth adhesive for bonding circuit members according to the present invention is an adhesive for bonding circuit members which is to be put between circuit electrodes facing each other; the circuit electrodes facing each other being pressed interposing the adhesive between them, to interconnect the electrodes electrically in the direction of pressing;

the adhesive being in multi-layer constitution having a third adhesive layer and a fourth adhesive layer which have physical properties different in value from each other.

The above adhesive may preferably have a modulus of elasticity after curing which is higher in the third adhesive layer than in the fourth adhesive layer, and the fourth adhesive layer has a modulus of elasticity of from 100 to 2,000 MPa at 40°C after curing.

The adhesive may also preferably have a coefficient of thermal expansion which is smaller in the third adhesive layer than in the fourth adhesive layer, and the third adhesive layer has a coefficient of thermal expansion at 30 to 100°C, of from 20 to 70 ppm/°C.

The adhesive may preferably have a glass transition temperature that is higher in the third adhesive layer than in the fourth adhesive layer, and the third adhesive layer has a glass transition temperature of 120°C or above.

At least one layer of the third and fourth adhesive layers may contain the inorganic filler in an amount of from 10 to 200 parts by weight based on 100 parts by weight of the adhesive resin composition.

5 The adhesive may contain conductive particles in an amount of from 0.1 to 30 parts by volume based on 100 parts by volume of the adhesive resin composition.

10 The adhesive may preferably have a modulus of elasticity of from 30 to 2,000 MPa at 40°C after the curing of the adhesive resin composition.

The adhesive resin composition may contain an epoxy resin, an acrylic rubber and a latent curing agent. The acrylic rubber may preferably be an acrylic rubber containing a glycidyl ether group in its molecule.

15 The adhesive may have the form of a film.

The circuit board of the present invention comprises; a first circuit member having first connecting terminals; and

20 a second circuit member having second connecting terminals;

the first connecting terminal and the second connecting terminal being disposed facing each other, and an adhesive being put between the first connecting terminal and the second connecting terminal which are disposed facing each other; and

the first connecting terminal and the second connecting

00752222 042301

terminal disposed facing each other being electrically interconnected by pressing with heating;

the adhesive being the adhesive for bonding circuit members according to the present invention.

5 Where the first circuit member having first connecting terminals is an inorganic insulating substrate having first connecting terminals and the second circuit member having second connecting terminals is an organic insulating substrate having second connecting terminals, the first
10 adhesive layer or the third adhesive layer of the adhesive having multi-layer constitution stands adhered on the side of the first circuit member.

 The adhesive for bonding circuit members according to the present invention is an adhesive for bonding circuit
15 members which is to be put between circuit electrodes facing each other; the circuit electrodes facing each other being pressed interposing the adhesive between them, to interconnect the electrodes electrically in the direction of pressing;

20 the adhesive comprising an adhesive resin composition and an inorganic filler; the inorganic filler being contained in an amount of from 10 to 200 parts by weight based on 100 parts by weight of the adhesive resin composition; or

25 the adhesive being in multi-layer constitution having a first adhesive layer containing the inorganic filler in

an amount of from 10 to 200 parts by weight based on 100 parts by weight of the adhesive resin composition and a second adhesive layer containing an adhesive resin composition as a major constituent. In such an adhesive for bonding circuit members according to the present invention, in which the inorganic filler is contained in an amount of from 10 to 200 parts by weight based on 100 parts by weight of the adhesive resin composition, the adhesive resin composition may preferably be a composition having a modulus of elasticity of from 30 to 2,000 MPa at 40°C after curing.

Here, the adhesive may have a modulus of elasticity at 40°C of from 100 to 5,000 MPa, and preferably higher than 2,000 MPa and not higher than 3,500 MPa.

An adhesive containing the adhesive resin composition having a modulus of elasticity of from 30 to 2,000 MPa at 40°C after curing and containing the inorganic filler to have a modulus of elasticity at 40°C which is higher than 2,000 MPa can relax its stress on account of the adhesive resin composition having a low modulus of elasticity and also can make its coefficient of thermal expansion small on account of the inorganic filler, making it possible to provide an adhesive for bonding circuit members which has a superior connection reliability.

The second adhesive layer containing an adhesive resin composition as a main ingredient may preferably contain no inorganic filler. However, in order to control properties,

it may contain the inorganic filler in an amount smaller than that in the first adhesive layer, e.g., less than 50% by weight, and preferably less than 20% by weight.

The second adhesive layer containing an adhesive resin composition as a main ingredient may be an adhesive layer having a modulus of elasticity at 40°C of from 100 to 2,000 MPa.

09752823 042301

The adhesive having multi-layer constitution as used in the present invention may preferably be provided in accordance with the magnitude of the modulus of elasticity or coefficient of thermal expansion of circuit members to be bonded to each other. More specifically, the adhesive may preferably be so provided that the third adhesive layer side having relatively a higher modulus of elasticity or smaller coefficient of thermal expansion or higher glass transition temperature is applied on the side of a circuit member having relatively a higher modulus of elasticity or smaller coefficient of thermal expansion, and the fourth adhesive layer side having relatively a lower modulus of elasticity or larger coefficient of thermal expansion or lower glass transition temperature is applied on the side of a circuit member having relatively a lower modulus of elasticity or larger coefficient of thermal expansion.

In the adhesive having multi-layer constitution as used in the present invention, when, e.g., a semiconductor chip and an organic insulating substrate are bonded to each other,

the fourth adhesive layer, constituting the face on the side of the organic insulating substrate, may preferably have a modulus of elasticity of from 100 to 2,000 MPa at 40°C after curing, for the purpose of relieving the stress due to a difference in coefficient of thermal expansion between the chip and the organic insulating substrate. The third adhesive layer, constituting the face on the side of the semiconductor chip, may have a modulus of elasticity of from 500 to 5,000 MPa at 40°C after curing, which is higher than that of the fourth adhesive layer.

For the purpose of relieving the stress due to a difference in coefficient of thermal expansion between the chip and the organic insulating substrate, the third adhesive layer constituting the face on the side of the semiconductor chip may preferably have a coefficient of thermal expansion at 30 to 100°C, of from 20 to 70 ppm/°C, and the fourth adhesive layer constituting the face on the side of the organic insulating substrate may preferably have a coefficient of thermal expansion at 30 to 100°C, of from 30 to 100 ppm/°C, which is larger than that of the third adhesive layer.

For the purpose of relieving the stress due to a difference in coefficient of thermal expansion between the chip and the organic insulating substrate, the third adhesive layer constituting the face on the side of the semiconductor chip may preferably have a glass transition

temperature of 120°C or higher and also 180°C or lower, and the fourth adhesive layer constituting the face on the side of the organic insulating substrate may preferably have a glass transition temperature lower than that of the third
5 adhesive layer.

At least one layer of the third and fourth adhesive layers may contain the inorganic filler.

09762822-042301
The coefficient of thermal expansion and glass transition temperature of an adhesive film cured product
10 corresponding to a stage after the adhesive has been applied may be measured with, e.g., a thermomechanical tester TM-7000 (tensile mode; load: 5 gf; heating rate: 5°C/minute), manufactured by Shinku-Riko Inc. Here, the adhesive film is cured under the same conditions as heating temperature
15 and time in the step of bonding. The curing of the adhesive film may be effected by immersing it in an oil bath. Such an adhesive film cured product is a product in which 90% or more of heat of the total curing exotherm has been liberated in the measurement with a DSC (differential
20 scanning calorimeter).

As the adhesive resin composition used in the present invention, usable is a mixture of an epoxy resin with any of latent curing agents such as imidazole types, hydrazide types, boron trifluoride-amine complexes, sulfonium salts,
25 amine-imides, polyamine salts and dicyandiamide. In order to relax the stress due to a difference in coefficient of

thermal expansion between circuit members, preferred is an adhesive resin composition having a modulus of elasticity of from 30 to 2,000 MPa at 40°C after curing.

For example, as an adhesive resin composition that can achieve good flow properties and high connection reliability at the time of bonding, preferred are those prepared by mixing an acrylic rubber in the mixture of an epoxy resin with any of latent curing agents such as imidazole types, hydrazide types, boron trifluoride-amine complexes, sulfonium salts, amine-imides, polyamine salts and dicyandiamide, so mixing them as to provide the modulus of elasticity of from 30 to 2,000 MPa at 40°C after curing.

The modulus of elasticity of an adhesive resin composition cured product corresponding to a stage after the adhesive resin composition has been applied may be measured by the DVE method using, e.g., RHEOSPECTRA DVE-4 (tensile mode; frequency: 10 Hz; heating rate: 5°C/minute; measured at -40°C up to 250°C), manufactured by Rheology Co.).

Here, the adhesive resin composition is cured under the same conditions as heating temperature and time in the step of bonding. The curing of the adhesive resin composition film may be effected by immersing it in an oil bath. Such an adhesive resin composition film cured product is a product in which 90% or more of heat of the total curing exotherm has been liberated in the measurement with the DSC.

The epoxy resin may include bisphenol type epoxy resins

derived from epichlorohydrin and bisphenol A, F, AD or the like; epoxy novolak resins derived from epichlorohydrin and phenol novolak or cresol novolak; naphthalene type epoxy resins having a skeleton containing a naphthalene ring; and epoxy compounds having at least two glycidyl groups in the molecule, such as glycidyl amine, glycidyl ether, biphenyl and alicyclics; any of which may be used alone or in combination of two or more types. As these epoxy resins, in order to prevent electron migration it is preferable to use high-purity products in which impurity ions (such as Na⁺ and Cl⁻), hydrolyzable chlorine and so forth have been reduced to 300 ppm or less.

The epoxy resin may preferably be a trifunctional or higher polyfunctional epoxy resin and/or a naphthalene type epoxy resin in order to ensure a low coefficient of thermal expansion and a high glass transition temperature. The trifunctional or higher polyfunctional epoxy resin may include phenol novolak type epoxy resins, cresol novolak type epoxy resins, trishydroxyphenylmethane type epoxy resins, tetraphenylolthane type epoxy resins, and dicyclopentadiene phenol type epoxy resins. In addition, the naphthalene type epoxy resin has a structure containing at least one naphthalene ring in one molecule, and may include naphthol types and naphthalenediol types.

The acrylic rubber may include polymers or copolymers having as a monomer component at least one of acrylic acid,

acrylate, methacrylate and acrylonitrile. In particular, copolymer type acrylic rubbers containing glycidyl acrylate or glycidyl methacrylate having a glycidyl ether group may preferably be used.

- 5 These acrylic rubbers may preferably be those having a molecular weight of 200,000 or more in view of improvement in cohesive force of the adhesive resin composition. If the acrylic rubber is mixed in an amount not more than 15% by weight in the adhesive resin composition, the composition
- 10 may have a modulus of elasticity higher than 2,000 MPa at 40°C after curing. If on the other hand it is in an amount more than 40% by weight, though a low modulus of elasticity is achievable, the composition may have so high a melt viscosity at the time of bonding that the molten adhesive
- 15 may be low removable at the interface to make it impossible to ensure electrical conduction between electrodes interconnected or between electrodes interconnected and conductive particles. Accordingly, the acrylic rubber may preferably be mixed in an amount of from 15 to 40% by weight.
- 20 These acrylic rubbers mixed in the adhesive resin composition have a peak temperature at about 40 to 60°C, of dielectric dissipation factor due to the rubber component, and hence the adhesive composition can be made to have a low modulus of elasticity.
- 25 The adhesive resin composition may preferably have a modulus of elasticity of from 30 to 2,000 MPa at 40°C after

curing. The adhesive may have a modulus of elasticity of from 100 to 5,000 MPa at 40°C after curing, and may have one higher than 2,000.

A thermoplastic resin such as a phenoxy resin may also
5 be mixed in the adhesive in order to more improve
film-forming properties. In particular, the phenoxy resin
is preferred because it has characteristic features that,
e.g., it is structurally similar to the epoxy resin and hence
has good compatibility with, and adhesion to, the epoxy
10 resin. To form film, an adhesive composition comprised of
at least these epoxy resin, acrylic rubber, phenoxy resin
and latent curing agent and conductive particles may be
dissolved or dispersed in an organic solvent to prepare a
liquid material, which may then be coated on the surface
15 of a film-releasable substrate, followed by removal of the
solvent at a temperature lower than the curing-agent
activation temperature. The solvent used here may
preferably be a mixed solvent of an aromatic hydrocarbon
type solvent and an oxygen-containing solvent in order to
20 improve solubility of materials.

The inorganic filler used in the present invention may
include, but not particularly limited to, e.g., powders of
fused silica, crystalline silica, calcium silicate, alumina,
calcium carbonate and the like. The inorganic filler may
25 be mixed in an amount of from 10 to 200 parts by weight based
on 100 parts by weight of the adhesive resin composition.

09762823-042301

The more the filler is mixed, the more effective it is to ensure a low coefficient of thermal expansion. However, its mixing in a large quantity may cause faulty conduction because the adhesive may have a low adhesion or may be low removable at the bonding part. If it is mixed in a small quantity, any low coefficient of thermal expansion may be ensured. Accordingly, it may preferably be mixed in an amount of from 20 to 90 parts by weight. In addition, it may have an average particle diameter smaller than 3 μm so that any faulty conduction at the bonding part can be prevented. In addition, for the purpose of preventing resin flowability from lowering and chip's passivation film from being damaged at the time of bonding, it is preferable to use a spherical filler.

15 In the adhesive of the present invention, conductive particles may be mixed and dispersed for the purpose of intentionally providing anisotropic conductivity in order to assimilate any uneven height of chip bumps or substrate electrodes. In the present invention, the conductive particles may be particles of metals as exemplified by Au, Ag, Cu and solder, and may preferably be those comprising spherical core materials of polymers such as polystyrene provided thereon with conductive layers of Ni, Cu, Au, solder or the like. In addition, surface layers of Sn, Au, solder or the like may be formed on the surfaces of conductive particles. Such particles must have a particle diameter

that is smaller than the minimum gap of substrate electrodes.

Where the electrodes have uneven height, the particles may preferably have a particle diameter that is larger than the uneven height, and preferably from 1 to 10 μm . In addition, the conductive particles may be dispersed in the adhesive in an amount of from 0.1 to 30 parts by volume, and preferably from 0.2 to 15 parts by volume, based on 100 parts by volume of the adhesive resin composition.

The adhesive of the present invention may be used as a film adhesive.

To obtain the film adhesive, an adhesive composition comprised of the epoxy resin, acrylic rubber, latent curing agent and so forth may be dissolved or dispersed in an organic solvent to prepare a liquid material, which may then be coated on the surface of a film-releasable substrate, followed by removal of the solvent at a temperature lower than the curing-agent activation temperature.

A film adhesive having multi-layer constitution may be obtained by a method in which a first or third film adhesive and a second or fourth film adhesive may individually be formed by coating on the surface of a separator film (film-releasable substrate) comprised of polyethylene terephthalate, fluorine type resin or the like and thereafter the first or third film adhesive and the second or fourth film adhesive are laminated by pressing or by pressing and simultaneously heating to obtain a film

adhesive comprised of the first or third film adhesive and the second or fourth film adhesive, or a method in which the first or third film adhesive (or the second or fourth film adhesive) is formed on the surface of the separator film and further thereon the second or fourth film adhesive (or the first or third film adhesive) is superposingly formed by coating to obtain a film adhesive comprised of the first or third film adhesive and the second or fourth film adhesive.

The film adhesive obtained by lamination of the first or third film adhesive and the second or fourth film adhesive may preferably be in a thickness of from 20 to 120 μm in total. The first or third film adhesive and the second or fourth film adhesive may individually preferably be in a thickness ratio in the range of first or third film adhesive : second or fourth film adhesive = 1:9 to 9:1. Especially when semiconductor chips are bonded to an organic insulating substrate, the ratio may preferably be in the range of first or third film adhesive : second or fourth film adhesive = 3:7 to 7:3.

The film adhesive may preferably have a layer thickness larger than the gap between the first and the second circuit members, and should commonly have a layer thickness larger by at least 5 μm than the gap.

In the present invention, as the circuit members, usable are chip component parts such as semiconductor chips,

resistor chips and capacitor chips, printed substrates, and flexible wiring boards comprised of polyimide or polyester as a base material.

5 The chip component parts comprise a non-metallic inorganic insulating substrate such as silicon, glass, ceramic or compound semiconductor substrate and formed thereon a large number of connecting terminals. The printed substrates and the flexible wiring boards comprised of polyimide or polyester as a base material comprise an
10 organic insulating substrate and formed thereon a large number of connecting terminals.

As a substrate on which the chip component parts are mounted, an organic insulating substrate having electrodes (connecting terminals) formed correspondingly to
15 semiconductor chip terminals may be used.

As the organic insulating substrate, usable are a synthetic-resin film of polyimide resin, polyester resin or the like, and a laminated sheet obtained by impregnating a glass substrate such as glass cloth or glass nonwoven
20 fabric with a resin such as polyimide resin, epoxy resin or phenol resin, followed by curing.

A multi-layer wiring board may be used which has electrodes to be connected to chip terminals, a surface insulating layer having these terminals formed thereon, a
25 given number of insulating layers, a given number of wiring layers provided between the respective insulating layers,

and holes having been made conductive through which the electrodes and the wiring layers are electrically interconnected.

Such a multi-layer wiring board may preferably be a built-up multi-layer substrate obtained by forming insulating layers and conductive circuit layers alternately on the surface of a base material having an insulating layer formed using glass cloth or on the surface of a wiring substrate having at least one conductor circuit.

As the surface insulating layer, a resin film may be used. As this resin film, usable are films of epoxy resins, polyimide resins, polyamide-imide resins, modified polyphenylene ether resins, phenoxy resins, amide-epoxy resins or phenolic resins, or mixtures, copolymers or the like of any of these; and films of heat-resistant thermoplastic engineering plastics such as polysulfone, polyether sulfone, polyether ether ketone, totally aromatic liquid-crystal polyesters, and fluorine resins. Resin films in which an organic or inorganic filler is contained may be used. As insulating layers formed of resins reinforced with a glass base material, prepregs may be used which are obtained by impregnating a glass substrate such as glass cloth or glass nonwoven fabric with a resin such as epoxy resin or phenol resin, followed by curing.

The circuit members are provided with connecting terminals that are usually in a large number (or may be single

in some cases). At least one set of the circuit members is so disposed that at least some of the connecting terminals provided on these circuit members face each other, and the adhesive is put between the connecting terminals disposed
5 facing each other, followed by pressing with heating to electrically interconnect the connecting terminals disposed facing each other, to make up a circuit board.

At least one set of circuit members is pressed with heating, whereupon the connecting terminals disposed facing
10 each other are electrically interconnected by direct contact or via the conductive particles of the anisotropic conductive adhesive.

On electrode pads of the semiconductor chip or substrate, bumps formed by plating and tips of gold wires
15 may be melted by means of a torch or the like to form gold balls, and these balls may be contact-bonded onto the electrode pads. Thereafter, projected electrodes such as wire bumps obtained by cutting wires may be provided so as to be used as the connecting terminals.

20 A process for producing the circuit board will be described taking the case of an instance in which a first circuit member comprised of an inorganic insulating substrate and a second circuit member comprised of an organic insulating substrate are bonded with a film
25 adhesive.

A first circuit member comprised of an inorganic

insulating substrate, having a first connecting terminal,
and a second circuit member comprised of an organic
insulating substrate, having a second connecting terminal,
are disposed in such a way that the first connecting terminal
5 and the second connecting terminal face each other, which
are so disposed that the adhesive for bonding circuit
members according to the present invention is put between
the first connecting terminal and the second connecting
terminal which have been disposed facing each other, in such
10 a way that the first or third adhesive layer is on the side
of the first circuit member, followed by pressing to
electrically interconnect the first connecting terminal and
the second connecting terminal disposed facing each other.

Thus, the circuit board of the present invention can be
15 produced.

Stated specifically, for example, firstly the surface
of a film, second or fourth adhesive layer is brought into
contact with the second circuit member to provisionally fix
the film adhesive to the second circuit member.

20 Subsequently, the electrodes of the first circuit member
are registered on the electrodes of the second circuit
member, where a load of 20 to 150 gf per electrode is applied
from the part on the side of the first circuit member, during
which heat is so applied for 10 to 20 seconds that the film
25 adhesive is heated to 180 to 200°C to cure the film adhesive.

Thus, the electrodes of the first circuit member and the

electrodes of the second circuit member are electrically interconnected and at the same time this state of connection between the first circuit member and the second circuit member is retained on account of the curing of the film adhesive.

An example in which a semiconductor chip is bonded to a mounting substrate will be described with reference to Figs. 1 and 2. Fig. 1 shows an example in which a semiconductor chip is bonded to a mounting substrate by means of an adhesive not containing any conductive particles.

Fig. 2 shows a bonded portion where a semiconductor chip is bonded to a mounting substrate by means of an adhesive containing conductive particles.

An electronic component device shown in Fig. 1 is constituted of a mounting substrate 20 and a semiconductor chip 10 mounted thereon. Incidentally, Fig. 1 shows part of the electronic component device. Actually, other component parts such as other semiconductor chips are mounted on the mounting substrate 20.

On the semiconductor chip 10, projected electrodes (bumps) serving as connecting electrodes 11 are formed on its one face. The chip is electrically interconnected to the mounting substrate via the connecting electrodes 11.

The mounting substrate 20 has a plurality of insulating layers 21 and 22, a plurality of wiring layers 32 and 33 disposed via the insulating layers 21 and 22, connecting

electrode terminals 31 for making connection with the connecting electrodes 11 of the semiconductor chip 10, and a conductor 34 provided through the insulating layers 21 and 22 to electrically interconnect wiring layers specified among the wiring layers 32 and 33. In order to pass the conductor 34 through the insulating layers, the insulating layers 21 and 22 are provided, at their necessary spots, with holes 25 for serving as through-holes. More

specifically, this mounting substrate constitutes a resin composite type multi-layer wiring board. Here, the wiring layers 32 are provided as an inner-layer circuit, and the wiring layers 33 are provided as an outer-layer circuit.

The connecting electrode terminals 31 function as a conductor circuit on which the chip is to be mounted.

The projected electrodes (bumps) which are connecting electrodes 11 provided on the semiconductor chip 10 are registered on the connecting electrode terminals 31 provided on the surface of the mounting substrate 20. A film adhesive 40 for bonding has been disposed between the semiconductor chip 10 and the mounting substrate 20. In this state, pressure and heat are applied from the part on the side of the semiconductor chip 10, whereby the adhesive 40 come to flow and then cure, so that the connecting electrodes 11 provided on the semiconductor chip 10 and the connecting electrode terminals 31 provided on the surface of the mounting substrate 20 come into direct mechanical

contact to attain electrical interconnection.

Where an adhesive 40 such as an anisotropic conductive adhesive having conductive particles 41 is used, as shown in Fig. 2 the connecting electrodes 11 are connected to the
5 connecting electrode terminals 31 in the state the conductive particles 41 are interposed between them, and simultaneously bonded and fixed there. In the case when the anisotropic conductive adhesive 40 is used and in the state where electrode surfaces facing each other to be bonded are
10 brought into pressure contact, the conduction between the electrodes facing each other is effected via the conductive particles interposed between them. In addition, between adjacent electrodes, the adhesive, though containing conductive particles, has the conductive particles in a low
15 density and hence exhibits no conductivity.

The mounting substrate 20 has at least one first insulating layer 21 formed of a resin reinforced with a glass base material, and a second insulating layer 22 which constitutes one layer at least on the side on which the
20 electronic component parts are bonded and fixed. Incidentally, in the example shown in Fig. 1, the second insulating layer 22 is also provided on the side different from the side on which the electronic component parts are bonded and fixed.

25 According to the adhesive of the present invention, any stress at the interface between the semiconductor chip and

the adhesive for bonding circuit members can be relaxed, and besides, in the case when it has a modulus of elasticity of from 30 to 2,000 MPa at 40°C as the adhesive resin composition, the stress generated in reliability tests such as the thermal shock test, PCT or solder bath immersion test can also be absorbed by the adhesive resin composition.

Hence, the adhesive may cause neither increase in connection resistance at bonded portions nor separation at adhesive layers even after the reliability tests, bringing about a great improvement in connection reliability. The present invention makes it possible to provide a gradation of physical properties in the thickness direction of the adhesive for bonding circuit members, and hence the adhesive can absorb internal stress generated in the reliability tests such as the thermal shock test, PCT or solder bath immersion test. Thus, the adhesive may cause neither increase in connection resistance at bonded portions nor separation at adhesive layers even after the reliability tests, bringing about a great improvement in connection reliability. In addition, the film adhesive is convenient to handle.

Accordingly, the adhesive of the present invention may preferably be used to make electrical connection between LCD (liquid-crystal display) panels and TAB (tape automated bonding) substrates, TAB substrates and flexible circuit substrates, LCD panels and IC chips, and IC chips and printed

wiring substrates only in the direction of pressing at the time of bonding.

The circuit board of the present invention can absorb the stress generated in the reliability tests, and may cause
5 neither increase in connection resistance at bonded portions nor separation at adhesive layers even after the reliability tests, bringing about a great improvement in connection reliability. In addition, in the circuit board of the present invention, the film adhesive having a small
10 coefficient of thermal expansion is used on the chip side and the stress generated at the interface between the chip and the adhesive can be relaxed. Thus, when the projected electrodes are provided on electrode pads of the chip, any separation of the projected electrodes from the electrode
15 pads can be made greatly less occur.

BRIEF DESCRIPTION OF THE DRAWINGS

Fig. 1 is a cross-sectional illustration of an example of the construction of an electronic component device
20 according to the present invention.

Fig. 2 is a cross-sectional illustration of an example of the state of connection between electronic component parts and a mounting substrate.

BEST MODES FOR PRACTICING THE INVENTION

Example 1

50 g of phenoxy resin and 125 g of acrylic rubber (molecular weight: 850,000) obtained by copolymerization of butyl acrylate (40 parts), ethyl acrylate (30 parts), acrylonitrile (30 parts) and glycidyl methacrylate (3 parts) were dissolved in 400 g of ethyl acetate to obtain a 30% solution.

Next, 325 g of liquid epoxy (epoxy equivalent weight: 185) containing a microcapsular latent curing agent was added to this solution, followed by stirring, where fused silica (average particle diameter: 0.5 μm) in an amount of 40 parts by weight based on 100 parts by weight of the adhesive resin composition and also 2% by volume of nickel particles (diameter: 3 μm) were dispersed to obtain a film coating fluid.

This film coating fluid was coated on a separator (silicone-treated polyethylene terephthalate film; thickness: 40 μm) by means of a roll coater, followed by drying at 100°C for 10 minutes to form an adhesive film a of 45 μm thick. This adhesive film a had a modulus of elasticity at 40°C of 800 MPa after curing as measured with a dynamic viscoelasticity measuring instrument on only an adhesive resin composition from which the fused silica and nickel particles were removed.

Next, using the adhesive film a thus obtained, a chip (10 mm x 10 mm; thickness: 0.5 mm) with gold bumps (area: 80 μm x 80 μm each; space: 30 μm ; height: 15 μm ; the number

of bumps: 288) was bonded to a Ni/Au-plated Cu circuit printed substrate in the manner as shown below.

First, the adhesive film a (12 mm x 12 mm) was stuck to the Ni/Au-plated Cu circuit printed substrate (electrode height: 20 μ m; thickness: 0.8 mm) at 80°C and 10 kgf/cm².

Thereafter, the separator was peeled, and the bumps of the chip were registered on the Ni/Au-plated Cu circuit printed substrate (thickness: 0.8 mm). Then, heat and pressure were applied from above the chip under conditions of 180°C, 30 g/bump and 20 seconds to effect main bonding.

Connection resistance after the main bonding was 6 m Ω at maximum per bump and 2 m Ω on the average, and insulation resistance was 10⁸ Ω or above. These values did not change even after 1,000-cycle treatment in a thermal shock test made at -55 to 125°C, after a PCT (121°C, 2 atmospheric pressure) made for 200 hours, and after 260°C solder bath immersion for 10 seconds, showing good connection reliability.

Example 2

50 g of phenoxy resin and 175 g of acrylic rubber (molecular weight: 850,000) obtained by copolymerization of butyl acrylate (40 parts), ethyl acrylate (30 parts), acrylonitrile (30 parts) and glycidyl methacrylate (3 parts) were dissolved in 525 g of ethyl acetate to obtain a 30% solution.

Next, 275 g of liquid epoxy (epoxy equivalent weight:

185) containing a microcapsular latent curing agent was added to this solution, followed by stirring, where fused silica (average particle diameter: $0.5\ \mu\text{m}$) in an amount of 60 parts by weight based on 100 parts by weight of the adhesive resin composition and also 2% by volume of nickel particles (diameter: $5\ \mu\text{m}$) were dispersed to obtain a film coating fluid.

This film coating fluid was coated on a separator (silicone-treated polyethylene terephthalate film; thickness: $40\ \mu\text{m}$) by means of a roll coater, followed by drying at 100°C for 10 minutes to form an adhesive film b of $45\ \mu\text{m}$ thick. This adhesive film b had a modulus of elasticity at 40°C of 400 MPa after curing as measured with a dynamic viscoelasticity measuring instrument on only an adhesive resin composition from which the fused silica and nickel particles were removed.

Next, using the adhesive film b thus obtained, a chip ($10\ \text{mm} \times 10\ \text{mm}$) with gold bumps (area: $80\ \mu\text{m} \times 80\ \mu\text{m}$ each; space: $30\ \mu\text{m}$; height: $15\ \mu\text{m}$; the number of bumps: 288) was bonded to a Ni/Au-plated Cu circuit printed substrate (electrode height: $20\ \mu\text{m}$; thickness: $0.8\ \text{mm}$) in the manner as shown below.

First, the adhesive film b ($12\ \text{mm} \times 12\ \text{mm}$) was stuck to the Ni/Au-plated Cu circuit printed substrate at 80°C and $10\ \text{kgf}/\text{cm}^2$. Thereafter, the separator was peeled, and the bumps of the chip were registered on the Ni/Au-plated Cu

circuit printed substrate. Then, heat and pressure were applied from above the chip under conditions of 170°C, 30 g/bump and 20 seconds to effect main bonding.

Connection resistance after the main bonding was 18 mΩ at maximum per bump and 8 mΩ on the average, and insulation resistance was 10⁸ Ω or above. These values did not change even after 1,000-cycle treatment in a thermal shock test made at -55 to 125°C, after a PCT (121°C, 2 atmospheric pressure) made for 200 hours, and after 260°C solder bath immersion for 10 seconds, showing good connection reliability.

Example 3

50 g of phenoxy resin and 100 g of acrylic rubber (molecular weight: 850,000) obtained by copolymerization of butyl acrylate (40 parts), ethyl acrylate (30 parts), acrylonitrile (30 parts) and glycidyl methacrylate (3 parts) were dissolved in 350 g of ethyl acetate to obtain a 30% solution.

Next, 350 g of liquid epoxy (epoxy equivalent weight: 185) containing a microcapsular latent curing agent was added to this solution, followed by stirring, where fused silica (average particle diameter: 0.5 μm) in an amount of 60 parts by weight based on 100 parts by weight of the adhesive resin composition and also 5% by volume of conductive particles obtained by forming Au layers on polystyrene cores (diameter: 5 μm) were dispersed to obtain

a film coating fluid.

09762823.042301
This film coating fluid was coated on a separator (silicone-treated polyethylene terephthalate film; thickness: 40 μm) by means of a roll coater, followed by
5 drying at 100°C for 10 minutes to form an adhesive film c of 45 μm thick. This adhesive film c had a modulus of elasticity at 40°C of 1,000 MPa after curing as measured with a dynamic viscoelasticity measuring instrument on only an
10 adhesive resin composition from which the fused silica and nickel particles were removed.

Next, using the adhesive film c thus obtained, a chip (10 mm x 10 mm; thickness: 0.5 mm) with gold bumps (area: 80 μm x 80 μm each; space: 30 μm ; height: 15 μm ; the number of bumps: 288) was bonded to a Ni/Au-plated Cu circuit
15 printed substrate (electrode height: 20 μm ; thickness: 0.8 mm) in the manner as shown below.

First, the adhesive film c (12 mm x 12 mm) was stuck to the Ni/Au-plated Cu circuit printed substrate at 80°C and 10 kgf/cm². Thereafter, the separator was peeled, and the
20 bumps of the chip were registered on the Ni/Au-plated Cu circuit printed substrate. Then, heat and pressure were applied from above the chip under conditions of 170°C, 30 g/bump and 20 seconds to effect main bonding.

Connection resistance after the main bonding was 5 m Ω
25 at maximum per bump and 1.5 m Ω on the average, and insulation resistance was 10⁸ Ω or above. These values did not change

even after 1,000-cycle treatment in a thermal shock test made at -55 to 125°C, after a PCT (121°C, 2 atmospheric pressure) made for 200 hours, and after 260°C solder bath immersion for 10 seconds, showing good connection

5 reliability.

Example 4

50 g of phenoxy resin and 100 g of acrylic rubber (molecular weight: 850,000) obtained by copolymerization of butyl acrylate (40 parts), ethyl acrylate (30 parts),
10 acrylonitrile (30 parts) and glycidyl methacrylate (3 parts) were dissolved in 350 g of ethyl acetate to obtain a 30% solution.

Next, 350 g of liquid epoxy (epoxy equivalent weight: 185) containing a microcapsular latent curing agent was
15 added to this solution, followed by stirring, where fused silica (average particle diameter: 0.5 μm) in an amount of 40 parts by weight based on 100 parts by weight of the adhesive resin composition and also 5% by volume of
conductive particles obtained by forming Au layers on
20 polystyrene cores (diameter: 5 μm) were dispersed to obtain a film coating fluid.

This film coating fluid was coated on a separator (silicone-treated polyethylene terephthalate film; thickness: 40 μm) by means of a roll coater, followed by
25 drying at 100°C for 10 minutes to form an adhesive film d of 45 μm thick. This adhesive film d had a modulus of

elasticity at 40°C of 1,000 MPa after curing as measured with a dynamic viscoelasticity measuring instrument on only an adhesive resin composition from which the fused silica and nickel particles were removed. In addition, the adhesive film d had an average coefficient of thermal expansion at 110 to 130°C of 111 ppm as measured by the TMA method.

Next, using the adhesive film d thus obtained, a chip (1.7 mm x 17 mm; thickness: 0.5 mm) with gold bumps (area: 50 μm x 50 μm each; 362 bumps; space: 20 μm ; height: 15 μm) was bonded to a glass substrate (thickness: 1.1 mm) with an ITO (yttrium tin oxide) circuit in the manner as shown below.

First, the adhesive film c (12 mm x 12 mm) was stuck to the glass substrate with an ITO circuit at 80°C and 10 kgf/cm². Thereafter, the separator was peeled, and the bumps of the chip were registered on the glass substrate with an ITO circuit. Then, heat and pressure were applied from above the chip under conditions of 180°C, 40 g/bump and 20 seconds to effect main bonding.

Connection resistance after the main bonding was 150 m Ω at maximum per bump and 80 m Ω on the average, and insulation resistance was 10⁸ Ω or above. These values did not change even after 1,000-cycle treatment in a thermal shock test made at -40 to 100°C and after a PCT (105°C, 1.2 atmospheric pressure) made for 100 hours, showing good connection reliability.

Example 5

50 g of phenoxy resin and 125 g of acrylic rubber (molecular weight: 850,000) obtained by copolymerization of butyl acrylate (40 parts), ethyl acrylate (30 parts), acrylonitrile (30 parts) and glycidyl methacrylate (3 parts) were dissolved in 400 g of ethyl acetate to obtain a 30% solution.

Next, 325 g of liquid epoxy (epoxy equivalent weight: 185) containing a microcapsular latent curing agent was added to this solution, followed by stirring, where fused silica (average particle diameter: 0.5 μm) in an amount of 60 parts by weight based on 100 parts by weight of the adhesive resin composition and also 2% by volume of nickel particles (diameter: 5 μm) were dispersed to obtain a film coating fluid.

This film coating fluid was coated on a separator (silicone-treated polyethylene terephthalate film; thickness: 40 μm) by means of a roll coater, followed by drying at 100°C for 10 minutes to form an adhesive film e of 45 μm thick. This adhesive film e had a modulus of elasticity at 40°C of 800 MPa after curing as measured with a dynamic viscoelasticity measuring instrument on only an adhesive resin composition from which the fused silica and nickel particles were removed.

Next, using the adhesive film e thus obtained, a bumpless chip (10 mm x 10 mm; thickness: 0.5 mm; pad

electrode: Al; pad diameter: 120 μm) was bonded to a
Ni/Au-plated Cu circuit printed substrate on the circuit
of which Ni/Au-plated Cu bumps (diameter: 100 μm ; space:
50 μm ; height: 15 μm ; the number of bumps: 200) were formed,
5 which was bonded in the manner as shown below.

First, the adhesive film e (12 mm x 12 mm) was stuck
to the Ni/Au-plated Cu circuit printed substrate (electrode
height: 20 μm ; thickness: 0.8 mm) at 80°C and 10 kgf/cm².

Thereafter, the separator was peeled, and the Al pads of
10 the chip were registered on the Ni/Au-plated Cu circuit
printed substrate (thickness: 0.8 mm) with Ni/Au-plated Cu
bumps. Then, heat and pressure were applied from above the
chip under conditions of 180°C, 30 g/bump and 20 seconds to
effect main bonding.

15 Connection resistance after the main bonding was 8 m Ω
at maximum per bump and 4 m Ω on the average, and insulation
resistance was 10⁸ Ω or above. These values did not change
even after 1,000-cycle treatment in a thermal shock test
made at -55 to 125°C, after a PCT (121°C, 2 atmospheric
20 pressure) made for 200 hours, and after 260°C solder bath
immersion for 10 seconds, showing good connection
reliability.

Example 6

25 50 g of phenoxy resin and 125 g of acrylic rubber
(molecular weight: 850,000) obtained by copolymerization
of butyl acrylate (40 parts), ethyl acrylate (30 parts),

acrylonitrile (30 parts) and glycidyl methacrylate (3 parts) were dissolved in 400 g of ethyl acetate to obtain a 30% solution.

Next, 325 g of liquid epoxy (epoxy equivalent weight: 185) containing a microcapsular latent curing agent was added to this solution, followed by stirring, where fused silica (average particle diameter: 0.5 μm) in an amount of 40 parts by weight based on 100 parts by weight of the adhesive resin composition was dispersed to obtain a film coating fluid.

This film coating fluid was coated on a separator (silicone-treated polyethylene terephthalate film; thickness: 40 μm) by means of a roll coater, followed by drying at 100°C for 10 minutes to form a first adhesive layer, adhesive film f (thickness: 25 μm). This adhesive film f had a modulus of elasticity at 40°C of 800 MPa after curing as measured with a dynamic viscoelasticity measuring instrument on only an adhesive resin composition from which the fused silica was removed.

A second adhesive layer, adhesive film g (thickness: 25 μm) was also formed in the same manner as the formation of the adhesive film g except that 2% by volume of nickel particles (diameter: 3 μm) were dispersed in place of the dispersing of the fused silica. The resultant adhesive film g had a modulus of elasticity at 40°C of 800 MPa.

Next, the adhesive film f and adhesive film g thus

obtained were laminated to obtain a composite film,
laminated film adhesive h.

Using this laminated film adhesive h, a chip (10 mm x
10 mm; thickness: 0.5 mm) with gold bumps (area: 80 μm x
5 80 μm each; space: 30 μm ; height: 15 μm ; the number of bumps:
288) was bonded to a Ni/Au-plated Cu circuit printed
substrate in the manner as shown below.

First, the adhesive film g (second adhesive layer) of
this laminated film adhesive h (12 mm x 12 mm) was stuck
10 to the Ni/Au-plated Cu circuit printed substrate (electrode
height: 20 μm ; thickness: 0.8 mm) at 80°C and 10 kgf/cm².

Thereafter, the separator was peeled, and the chip was faced
on the side of the adhesive film f (first adhesive layer),
where the bumps of the chip were registered on the
15 Ni/Au-plated Cu circuit printed substrate (thickness: 0.8
mm). Then, heat and pressure were applied from above the
chip under conditions of 180°C, 50 g/bump and 20 seconds to
effect main bonding.

Connection resistance after the main bonding was 6 m Ω
20 at maximum per bump and 2 m Ω on the average, and insulation
resistance was 10⁸ Ω or above. These values did not change
even after 1,000-cycle treatment in a thermal shock test
made at -55 to 125°C, after a PCT (121°C, 2 atmospheric
pressure) made for 200 hours, and after 260°C solder bath
25 immersion for 10 seconds, showing good connection
reliability.

Example 7

50 g of phenoxy resin and 175 g of acrylic rubber (molecular weight: 850,000) obtained by copolymerization of butyl acrylate (40 parts), ethyl acrylate (30 parts),
5 acrylonitrile (30 parts) and glycidyl methacrylate (3 parts) were dissolved in 525 g of ethyl acetate to obtain a 30% solution.

Next, 275 g of liquid epoxy (epoxy equivalent weight: 185) containing a microcapsular latent curing agent was
10 added to this solution, followed by stirring, where fused silica (average particle diameter: 1 μm) in an amount of 60 parts by weight based on 100 parts by weight of the adhesive resin composition was dispersed to obtain a film coating fluid.

15 This film coating fluid was coated on a separator (silicone-treated polyethylene terephthalate film; thickness: 40 μm) by means of a roll coater, followed by drying at 100°C for 10 minutes to form an adhesive film i (thickness: 20 μm) corresponding to the first adhesive layer.
20 This adhesive film i had a modulus of elasticity at 40°C of 400 MPa after curing as measured with a dynamic viscoelasticity measuring instrument on only an adhesive resin composition from which the fused silica was removed.

An adhesive film j (thickness: 20 μm) corresponding to
25 the second adhesive layer was also formed in the same manner as the formation of the adhesive film i except that 2% by

volume of nickel particles (diameter: 5 μm) were dispersed in place of the dispersing of the fused silica. The resultant adhesive film j had a modulus of elasticity at 40°C of 400 MPa.

5 Next, the adhesive film i and adhesive film j thus obtained were laminated to obtain a composite film, laminated film adhesive k. Using this laminated film adhesive k, a chip (10 mm x 10 mm; thickness: 0.5 mm) with gold bumps (area: 80 μm x 80 μm each; space: 30 μm ; height: 10 15 μm ; the number of bumps: 288) was bonded to a Ni/Au-plated Cu circuit printed substrate in the manner as shown below.

First, the adhesive film j (second adhesive layer) of this laminated film adhesive k (12 mm x 12 mm) was stuck to the Ni/Au-plated Cu circuit printed substrate (electrode 15 height: 20 μm ; thickness: 0.8 mm) at 80°C and 10 kgf/cm².

Thereafter, the separator was peeled, and the chip was faced on the side of the adhesive film i (first adhesive layer), where the bumps of the chip were registered on the Ni/Au-plated Cu circuit printed substrate (thickness: 0.8 20 mm). Then, heat and pressure were applied from above the chip under conditions of 180°C, 50 g/bump and 20 seconds to effect main bonding.

Connection resistance after the main bonding was 18 m Ω at maximum per bump and 8 m Ω on the average, and insulation 25 resistance was 10⁸ Ω or above. These values did not change even after 1,000-cycle treatment in a thermal shock test

made at -55 to 125°C, after a PCT (121°C, 2 atmospheric pressure) made for 200 hours, and after 260°C solder bath immersion for 10 seconds, showing good connection reliability.

5 Example 8

50 g of phenoxy resin and 100 g of acrylic rubber (molecular weight: 850,000) obtained by copolymerization of butyl acrylate (40 parts), ethyl acrylate (30 parts), acrylonitrile (30 parts) and glycidyl methacrylate (3
10 parts) were dissolved in 350 g of ethyl acetate to obtain a 30% solution.

Next, 350 g of liquid epoxy (epoxy equivalent weight: 185) containing a microcapsular latent curing agent was added to this solution, followed by stirring, where fused
15 silica (average particle diameter: 0.5 μm) in an amount of 60 parts by weight based on 100 parts by weight of the adhesive resin composition was dispersed to obtain a film coating fluid.

This film coating fluid was coated on a separator
20 (silicone-treated polyethylene terephthalate film; thickness: 40 μm) by means of a roll coater, followed by drying at 100°C for 10 minutes to form an adhesive film m (thickness: 25 μm) corresponding to the first adhesive layer.

This adhesive film m had a modulus of elasticity at 40°C
25 of 1,000 MPa after curing as measured with a dynamic viscoelasticity measuring instrument on only an adhesive

resin composition from which the fused silica was removed.

An adhesive film n (thickness: 25 μm) corresponding to the second adhesive layer was also formed in the same manner as the formation of the adhesive film m except that 5% by volume of conductive particles obtained by forming Au layers on polystyrene cores (diameter: 5 μm) were dispersed in place of the dispersing of the fused silica. The resultant adhesive film n had a modulus of elasticity at 40°C of 1,000 MPa.

Next, the adhesive film m and adhesive film n thus obtained were laminated to obtain a composite film, laminated film adhesive p. Using this laminated film adhesive p, a chip (10 mm x 10 mm; thickness: 0.5 mm) with gold bumps (area: 80 μm x 80 μm each; space: 30 μm ; height: 15 μm ; the number of bumps: 288) was bonded to a Ni/Au-plated Cu circuit printed substrate in the manner as shown below.

First, the adhesive film n (second adhesive layer) of this laminated film adhesive p (12 mm x 12 mm) was stuck to the Ni/Au-plated Cu circuit printed substrate (electrode height: 20 μm ; thickness: 0.8 mm) at 80°C and 10 kgf/cm².

Thereafter, the separator was peeled, and the chip was faced on the side of the adhesive film m (first adhesive layer), where the bumps of the chip were registered on the Ni/Au-plated Cu circuit printed substrate (thickness: 0.8 mm). Then, heat and pressure were applied from above the chip under conditions of 180°C, 50 g/bump and 20 seconds to

effect main bonding.

Connection resistance after the main bonding was 5 m Ω at maximum per bump and 1.5 m Ω on the average, and insulation resistance was 10⁸ Ω or above. These values did not change even after 1,000-cycle treatment in a thermal shock test made at -55 to 125°C, after a PCT (121°C, 2 atmospheric pressure) made for 200 hours, and after 260°C solder bath immersion for 10 seconds, showing good connection reliability.

10 Example 9

50 g of phenoxy resin and 125 g of acrylic rubber (molecular weight: 850,000) obtained by copolymerization of butyl acrylate (40 parts), ethyl acrylate (30 parts), acrylonitrile (30 parts) and glycidyl methacrylate (3 parts) were dissolved in 400 g of ethyl acetate to obtain a 30% solution.

Next, 325 g of liquid epoxy (epoxy equivalent weight: 185) containing a microcapsular latent curing agent was added to this solution, followed by stirring, where fused silica (average particle diameter: 0.5 μ m) in an amount of 60 parts by weight based on 100 parts by weight of the adhesive resin composition was dispersed to obtain a film coating fluid.

This film coating fluid was coated on a separator (silicone-treated polyethylene terephthalate film; thickness: 25 μ m) by means of a roll coater, followed by

drying at 100°C for 10 minutes to form an adhesive film q (thickness: 25 μm) corresponding to the first adhesive layer.

This adhesive film q had a modulus of elasticity at 40°C of 800 Mpa after curing as measured with a dynamic
5 viscoelasticity measuring instrument on only an adhesive resin composition from which the fused silica was removed.

An adhesive film r (thickness: 25 μm) corresponding to the second adhesive layer was also formed in the same manner as the formation of the adhesive film q except that 2% by
10 volume of nickel particles (diameter: 3 μm) were dispersed in place of the dispersing of the fused silica. The resultant adhesive film r had a modulus of elasticity at 40°C of 800 MPa.

Next, the adhesive film q and adhesive film r thus
15 obtained were laminated to obtain a composite film, laminated film adhesive s.

Using this laminated film adhesive s, a bumpless chip (10 mm x 10 mm; thickness: 0.5 mm; pad electrode: Al; pad diameter: 120 μm) was bonded to a Ni/Au-plated Cu circuit
20 printed substrate on the circuit of which Ni/Au-plated Cu bumps (diameter: 100 μm ; space: 50 μm ; height: 15 μm ; the number of bumps: 200) were formed, which was bonded in the manner as shown below.

First, the adhesive film r (second adhesive layer) of
25 this laminated film adhesive s (12 mm x 12 mm) was stuck at 80°C and 10 kgf/cm², to the Ni/Au-plated Cu circuit printed

substrate on which Ni/Au-plated Cu bumps (diameter: 100 μm ; space: 50 μm ; height: 15 μm ; the number of bumps: 200) were formed. Thereafter, the separator was peeled, and the chip was faced on the side of the adhesive film q (first adhesive layer), where the bumps of the chip were registered on the Ni/Au-plated Cu circuit printed substrate (thickness: 0.8 mm). Then, heat and pressure were applied from above the chip under conditions of 180°C, 50 g/bump and 20 seconds to effect main bonding.

Connection resistance after the main bonding was 8 m Ω at maximum per bump and 4 m Ω on the average, and insulation resistance was 10⁸ Ω or above. These values did not change even after 1,000-cycle treatment in a thermal shock test made at -55 to 125°C, after a PCT (121°C, 2 atmospheric pressure) made for 200 hours, and after 260°C solder bath immersion for 10 seconds, showing good connection reliability.

Example 10

195 g of phenoxy resin and 130 g of polyfunctional epoxy resin (epoxy equivalent weight: 212) were dissolved in 1,083 g of ethyl acetate to obtain a 30% solution.

Next, 325 g of liquid epoxy (epoxy equivalent weight: 185) containing a microcapsular latent curing agent was added to this solution, followed by stirring, where 2% by volume of nickel particles (diameter: 5 μm) was also dispersed to obtain a film coating fluid.

09762822, 042301

This film coating fluid was coated on a separator (silicone-treated polyethylene terephthalate film; thickness: 40 μm) by means of a roll coater, followed by drying at 100°C for 10 minutes to form an adhesive film t (thickness: 25 μm) corresponding to the third adhesive layer. This adhesive film t had a coefficient of thermal expansion of 45 ppm at 30 to 100°C after curing, a glass transition temperature of 150°C and a modulus of elasticity at 40°C of 2,600 MPa.

10 50 g of phenoxy resin and 100 g of acrylic rubber (molecular weight: 850,000) obtained by copolymerization of butyl acrylate (40 parts), ethyl acrylate (20 parts), acrylonitrile (30 parts) and glycidyl methacrylate (3 parts) were also dissolved in 500 g of ethyl acetate to obtain
15 a 30% solution.

Next, 350 g of liquid epoxy (epoxy equivalent weight: 185) containing a microcapsular latent curing agent was added to this solution, followed by stirring, where 2% by volume of nickel particles (diameter: 5 μm) was also
20 dispersed to obtain a film coating fluid.

This film coating fluid was coated on a separator (silicone-treated polyethylene terephthalate film; thickness: 40 μm) by means of a roll coater, followed by drying at 100°C for 10 minutes to form an adhesive film u (thickness: 25 μm) corresponding to the fourth adhesive
25 layer. This adhesive film u had a coefficient of thermal

expansion of 70 ppm at 30 to 100°C after curing, a glass transition temperature of 125°C and a modulus of elasticity at 40°C of 1,000 MPa.

Next, the adhesive film t and adhesive film u thus
5 obtained were laminated to obtain a composite film,
laminated film adhesive v (thickness: 50 μ m).

Then, using this laminated film adhesive v, a chip
(size: 10 mm x 10 mm; thickness: 0.55 mm) with gold bumps
(height: 30 μ m; the number of bumps: 184) was bonded to a
10 Ni/Au-plated Cu circuit printed substrate (electrode
height: 20 μ m; substrate thickness: 0.8 mm) in the manner
as shown below.

First, the adhesive film u (fourth adhesive layer) of
this laminated film adhesive v (size: 12 mm x 12 mm) was
15 provisionally bonded to the Ni/Au-plated Cu circuit printed
substrate with the adhesive film u's face set on the side
of the printed substrate, under conditions of 60°C and 0.5
MPa. After the step of provisional bonding, the bumps of
the chip were registered on the Ni/Au-plated Cu circuit
20 printed substrate, and the chip was mounted on the laminated
film adhesive v. Subsequently, heat and pressure were
applied from above the chip under conditions of 180°C, 50
g/bump and 20 seconds to effect main bonding.

Connection resistance after the main bonding was 10 m Ω
25 at maximum per bump and 2 m Ω on the average, and insulation
resistance was 10⁸ Ω or above. These values did not change

during continuous (in situ) measurement of resistance in the course of a 1,000-cycle thermal shock test made at -55 to 125°C and a PCT made for 500 hours at 110°C and 85%RH, showing a good connection reliability.

5 Example 11

195 g of phenoxy resin and 130 g of polyfunctional epoxy resin (epoxy equivalent weight: 212) were dissolved in 1,083 g of ethyl acetate to obtain a 30% solution.

Next, 325 g of liquid epoxy (epoxy equivalent weight: 10 185) containing a microcapsular latent curing agent was added to this solution, followed by stirring, where fused silica (average particle diameter: 0.5 μ m) in an amount of 20 parts by weight based on 100 parts by weight of the adhesive resin composition and also 2% by volume of nickel 15 particles (diameter: 5 μ m) were dispersed to obtain a film coating fluid.

This film coating fluid was coated on a separator (silicone-treated polyethylene terephthalate film; thickness: 40 μ m) by means of a roll coater, followed by 20 drying at 100°C for 10 minutes to form an adhesive film w (thickness: 25 μ m) corresponding to the third adhesive layer. This adhesive film w had a coefficient of thermal expansion of 38 ppm at 30 to 100°C after curing, a glass transition temperature of 153°C and a modulus of elasticity at 40°C of 25 3,000 MPa.

50 g of phenoxy resin and 100 g of acrylic rubber

(molecular weight: 850,000) obtained by copolymerization of butyl acrylate (40 parts), ethyl acrylate (20 parts), acrylonitrile (30 parts) and glycidyl methacrylate (3 parts) were also dissolved in 500 g of ethyl acetate to obtain a 30% solution.

Next, 350 g of liquid epoxy (epoxy equivalent weight: 185) containing a microcapsular latent curing agent was added to this solution, followed by stirring, where fused silica (average particle diameter: 0.5 μm) in an amount of 20 parts by weight based on 100 parts by weight of the adhesive resin composition and also 2% by volume of nickel particles (diameter: 5 μm) were dispersed to obtain a film coating fluid.

This film coating fluid was coated on a separator (silicone-treated polyethylene terephthalate film; thickness: 40 μm) by means of a roll coater, followed by drying at 100°C for 10 minutes to form an adhesive film x (thickness: 25 μm) corresponding to the fourth adhesive layer. This adhesive film x had a coefficient of thermal expansion of 60 ppm at 30 to 100°C after curing, a glass transition temperature of 127°C and a modulus of elasticity at 40°C of 1,400 MPa.

Next, the adhesive film w and adhesive film x thus obtained were laminated to obtain a composite film, laminated film adhesive y (thickness: 50 μm).

Then, using this laminated film adhesive y, a chip

(size: 10 mm x 10 mm; thickness: 0.55 mm) with gold bumps (height: 30 μ m; the number of bumps: 184) was bonded to a Ni/Au-plated Cu circuit printed substrate (electrode height: 20 μ m; substrate thickness: 0.8 mm) in the manner as shown below.

The adhesive film x (fourth adhesive layer) of this laminated film adhesive y (size: 12 mm x 12 mm) was provisionally bonded to the Ni/Au-plated Cu circuit printed substrate with the adhesive film x's face set on the side of the printed substrate, under conditions of 60°C and 0.5 MPa. After the step of provisional bonding, the bumps of the chip were registered on the Ni/Au-plated Cu circuit printed substrate, and the chip was mounted on the laminated film adhesive y. Subsequently, heat and pressure were applied from above the chip under conditions of 180°C, 50 g/bump and 20 seconds to effect main bonding.

Connection resistance after the main bonding was 10 m Ω at maximum per bump and 2 m Ω on the average, and insulation resistance was 10⁸ Ω or above. These values did not change during continuous (in situ) measurement of resistance in the course of a 1,000-cycle thermal shock test made at -55 to 125°C and a PCT made for 500 hours at 110°C and 85%RH, showing good connection reliability.

Comparative Example 1

Using the laminated film adhesive v obtained in Example 10, a chip (size: 10 mm x 10 mm; thickness: 0.55 mm) with

gold bumps (height: 30 μm ; the number of bumps: 184) was bonded to a Ni/Au-plated Cu circuit printed substrate (electrode height: 20 μm ; substrate thickness: 0.8 mm) in the same manner as in Example 10 except that, in the present
5 Comparative Example, the face of the adhesive film t (third adhesive layer) of the laminated film adhesive v (size: 12 mm x 12 mm) was set on the side of the printed substrate.

Connection resistance after the main bonding was 10 m Ω at maximum per bump and 2 m Ω on the average, and insulation
10 resistance was $10^8 \Omega$ or above. However, these values changed in the course of a 500-cycle thermal shock test made at -55 to 125°C and a PCT made for 300 hours at 110°C and 85%RH, resulting in faulty electrical conduction.

Comparative Example 2

15 195 g of phenoxy resin and 130 g of polyfunctional epoxy resin (epoxy equivalent weight: 212) were dissolved in 1,083 g of ethyl acetate to obtain a 30% solution.

Next, 325 g of liquid epoxy (epoxy equivalent weight: 185) containing a microcapsular latent curing agent was
20 added to this solution, followed by stirring, where 2% by volume of nickel particles (diameter: 5 μm) was also dispersed to obtain a film coating fluid.

This film coating fluid was coated on a separator (silicone-treated polyethylene terephthalate film;
25 thickness: 40 μm) by means of a roll coater, followed by drying at 100°C for 10 minutes to form an adhesive film z

of 50 μm thick. The adhesive film z had a coefficient of thermal expansion of 45 ppm at 30 to 100°C after curing, a glass transition temperature of 150°C and a modulus of elasticity at 40°C of 2,600 MPa.

5 Next, using only the adhesive film z thus obtained, a chip (size: 10 mm x 10 mm; thickness: 0.55 mm) with gold bumps (height: 30 μm ; the number of bumps: 184) was bonded to a Ni/Au-plated Cu circuit printed substrate (electrode height: 20 μm ; substrate thickness: 0.8 mm) in the manner
10 as shown below.

First, the adhesive film z was provisionally bonded to the Ni/Au-plated Cu circuit printed substrate under conditions of 60°C and 0.5 MPa. After the step of provisional bonding, the bumps of the chip were registered
15 on the Ni/Au-plated Cu circuit printed substrate, and the chip was mounted on the adhesive film z. Subsequently, heat and pressure were applied from above the chip under conditions of 180°C, 50 g/bump and 20 seconds to effect main bonding.

20 Connection resistance after the main bonding was 10 m Ω at maximum per bump and 3 m Ω on the average, and insulation resistance was $10^8 \Omega$ or above. However, these values changed after a 300-cycle thermal shock test made at -55 to 125°C and after 260°C solder bath immersion for 10 seconds,
25 resulting in faulty electrical conduction. As a result of cross-sectional observation of the bonded portions,

separation of the adhesive film at its interface was observed at some part where the faulty electrical conduction occurred.

Comparative Example 3

5 50 g of phenoxy resin and 100 g of acrylic rubber (molecular weight: 850,000) obtained by copolymerization of butyl acrylate (40 parts), ethyl acrylate (20 parts), acrylonitrile (30 parts) and glycidyl methacrylate (3 parts) were also dissolved in 500 g of ethyl acetate to obtain
10 a 30% solution.

Next, 350 g of liquid epoxy (epoxy equivalent weight: 185) containing a microcapsular latent curing agent was added to this solution, followed by stirring, where 2% by volume of nickel particles (diameter: 5 μ m) was also
15 dispersed to obtain a film coating fluid.

This film coating fluid was coated on a separator (silicone-treated polyethylene terephthalate film; thickness: 40 μ m) by means of a roll coater, followed by drying at 100°C for 10 minutes to form an adhesive film α
20 of 25 μ m thick. This adhesive film α had a coefficient of thermal expansion of 60 ppm at 30 to 100°C after curing, a glass transition temperature of 125°C and a modulus of elasticity at 40°C of 1,000 MPa.

Next, using only the adhesive film α thus obtained, a
25 chip (size: 10 mm x 10 mm; thickness: 0.55 mm) with gold bumps (height: 30 μ m; the number of bumps: 184) was bonded

to a Ni/Au-plated Cu circuit printed substrate (electrode height: 20 μm ; substrate thickness: 0.8 mm) in the manner as shown below.

First, the adhesive film α was provisionally bonded to the Ni/Au-plated Cu circuit printed substrate under conditions of 60°C and 0.5 MPa. After the step of provisional bonding, the bumps of the chip were registered on the Ni/Au-plated Cu circuit printed substrate, and the chip was mounted on the adhesive film α . Subsequently, heat and pressure were applied from above the chip under conditions of 180°C, 50 g/bump and 20 seconds to effect main bonding.

Connection resistance after the main bonding was 10 m Ω at maximum per bump and 2 m Ω on the average, and insulation resistance was 10⁸ Ω or above. However, these values changed during a high-temperature thermal shock test in a 30-cycle thermal shock test made at -55 to 125°C, so that the electrical conduction became poor.

POSSIBILITY OF INDUSTRIAL APPLICATION

As described above, the present invention enables production of circuit boards that may cause neither increase in connection resistance at bonded portions nor separation at adhesive layers and have greatly improved in connection reliability.

Claims

1 1. An adhesive for bonding circuit members which is
2 to be put between circuit electrodes facing each other;
3 said circuit electrodes facing each other being pressed
4 interposing the adhesive between them, to interconnect
5 the electrodes electrically in the direction of pressing;

6 said adhesive comprising an adhesive resin
7 composition and an inorganic filler;

8 said inorganic filler being contained in an amount
9 of from 10 to 200 parts by weight based on 100 parts by
10 weight of the adhesive resin composition.

1 2. An adhesive for bonding circuit members which is
2 to be put between circuit electrodes facing each other;
3 said circuit electrodes facing each other being pressed
4 interposing the adhesive between them, to interconnect
5 the electrodes electrically in the direction of pressing;

6 said adhesive being in multi-layer constitution
7 having;

8 a first adhesive layer comprising an adhesive resin
9 composition and an inorganic filler and containing the
10 inorganic filler in an amount of from 10 to 200 parts by
11 weight based on 100 parts by weight of the adhesive resin

12 composition; and
13 a second adhesive layer containing an adhesive resin
14 composition as a main ingredient.

1 3. An adhesive for bonding circuit members which is
2 to be put between circuit electrodes facing each other;
3 said circuit electrodes facing each other being pressed
4 interposing the adhesive between them, to interconnect
5 the electrodes electrically in the direction of pressing;
6 said adhesive being in multi-layer constitution
7 having;

8 a first adhesive layer comprising an adhesive resin
9 composition and an inorganic filler and containing the
10 inorganic filler in an amount of from 10 to 200 parts by
11 weight based on 100 parts by weight of the adhesive resin
12 composition; and

13 a second adhesive layer containing an adhesive resin
14 composition and having a modulus of elasticity of from
15 100 to 2,000 MPa at 40°C after curing.

1 4. An adhesive for bonding circuit members which is
2 to be put between circuit electrodes facing each other;
3 said circuit electrodes facing each other being pressed
4 interposing the adhesive between them, to interconnect

5 the electrodes electrically in the direction of pressing;
 6 said adhesive comprising an adhesive resin
 7 composition and an inorganic filler,
 8 said adhesive having an average coefficient of
 9 thermal expansion of 200 ppm/°C or below at 110 to 130°C
 10 after curing.

1 5. The adhesive for bonding circuit members
 2 according to claim 4, which has an average coefficient
 3 of thermal expansion of from 30 to 200 ppm/°C at 110 to
 4 130°C after curing of the adhesive.

1 6. An adhesive for bonding circuit members which is
 2 to be put between circuit electrodes facing each other;
 3 said circuit electrodes facing each other being pressed
 4 interposing the adhesive between them, to interconnect
 5 the electrodes electrically in the direction of pressing;
 6 said adhesive being in multi-layer constitution
 7 having a third adhesive layer and a fourth adhesive layer
 8 which have physical properties different in value from
 9 each other.

1 7. The adhesive for bonding circuit members
 2 according to claim 6, wherein said first adhesive layer

3 has a modulus of elasticity after curing which is higher
4 than the modulus of elasticity after curing of said second
5 adhesive layer.

1 8. The adhesive for bonding circuit members
2 according to claim 7, wherein said fourth adhesive layer
3 has a modulus of elasticity of from 100 to 2,000 MPa at
4 40°C after curing.

1 9. The adhesive for bonding circuit members
2 according to claim 6, wherein said third adhesive layer
3 has a coefficient of thermal expansion which is smaller
4 than the coefficient of thermal expansion of the fourth
5 adhesive layer.

1 10. The adhesive for bonding circuit members
2 according to claim 9, wherein said third adhesive layer
3 has a coefficient of thermal expansion at 30 to 100°C,
4 of from 20 to 70 ppm/°C.

1 11. The adhesive for bonding circuit members
2 according to claim 6, wherein said third adhesive layer
3 has a glass transition temperature which is higher than
4 the glass transition temperature of the fourth adhesive

5 layer.

1 12. The adhesive for bonding circuit members
2 according to claim 11, wherein said third adhesive layer
3 has a glass transition temperature of 120°C or above.

1 13. The adhesive for bonding circuit members
2 according to any one of claims 7, 9 or 11, wherein at least
3 one layer of said third and fourth adhesive layers
4 contains;

5 the adhesive resin composition; and
6 the inorganic filler in an amount of from 10 to 200
7 parts by weight based on 100 parts by weight of the
8 adhesive resin composition.

1 14. The adhesive for bonding circuit members
2 according to any one of claims 1, 2, 3, 4 or 13, wherein
3 said inorganic filler has an average particle diameter
4 of 3 μm or smaller.

1 15. The adhesive for bonding circuit members
2 according to any one of claims 1 to 14, comprising
3 conductive particles in an amount of from 0.1 to 30 parts
4 by volume based on 100 parts by volume of the adhesive

095222-042201

5 resin composition.

1 16. The adhesive for bonding circuit members
2 according to any one of claims 1, 2, 3, 4, 13 or 14,
3 comprising conductive particles having a larger average
4 particle diameter than the average particle diameter of
5 said inorganic filler, in an amount of from 0.1 to 30 parts
6 by volume based on 100 parts by volume of the adhesive
7 resin composition.

1 17. The adhesive for bonding circuit members
2 according to any one of claims 1 to 16, which has a modulus
3 of elasticity of from 30 to 2,000 MPa at 40°C after the
4 curing of the adhesive resin composition.

1 18. The film adhesive for bonding circuits
2 according to any one of claims 1 to 17, wherein said
3 adhesive resin composition contains an epoxy resin and
4 a latent curing agent.

1 19. The adhesive for bonding circuit members
2 according to any one of claims 1 to 18, wherein said
3 adhesive resin composition contains an epoxy resin, an
4 acrylic rubber and a latent curing agent.

1 20. The adhesive for bonding circuit members
2 according to claim 19, wherein said acrylic rubber
3 contains a glycidyl ether group in the molecule.

1 21. The adhesive for bonding circuit members
2 according to any one of claims 1 to 20, which has the form
3 of a film.

1 22. A circuit board comprising;
2 a first circuit member having a first connecting
3 terminal; and
4 a second circuit member having a second connecting
5 terminal;

6 said first connecting terminal and the second
7 connecting terminal being disposed facing each other, and
8 an adhesive being put between the first connecting
9 terminal and the second connecting terminal which are
10 disposed facing each other; and

11 said first connecting terminal and the second
12 connecting terminal disposed facing each other being
13 electrically interconnected by pressing;

14 said adhesive being the adhesive for bonding circuit
15 members according to any one of claims 1 to 21,

1 23. The circuit board according to claim 22,
2 wherein;
3 said first circuit member is an inorganic insulating
4 substrate;
5 said second circuit member is an organic insulating
6 substrate;
7 said adhesive is the adhesive for bonding circuit
8 members according to claim 2 or 3; and
9 at least any of said first adhesive layer stands
10 adhered on the side of said first circuit member.

1 24. The circuit board according to claim 22,
2 wherein;
3 said first circuit member is an inorganic insulating
4 substrate;
5 said second circuit member is an organic insulating
6 substrate;
7 said adhesive is the adhesive for bonding circuit
8 members according to any one of claims 7 to 13; and
9 at least any of said third adhesive layer stands
10 adhered on the side of said first circuit member.

1 25. The circuit board according to claim 23 or 24,
2 wherein;

3 said first circuit member is a semiconductor chip.

1 26. A process for producing a circuit board,
2 comprising the steps of;
3 disposing a first circuit member comprised of an
4 inorganic insulating substrate, having a first
5 connecting terminal, and a second circuit member
6 comprised of an organic insulating substrate, having a
7 second connecting terminal, in such a way that the first
8 connecting terminal and the second connecting terminal
9 face each other;

10 said circuit members being so disposed that the
11 adhesive for bonding circuit members according to claim
12 2 or 3 is put between said first connecting terminal and
13 said second connecting terminal which have been disposed
14 facing each other, in such a way that said first adhesive
15 layer is on the side of said first circuit member; and
16 pressing the resultant circuit members to
17 electrically interconnect said first connecting terminal
18 and said second connecting terminal disposed facing each
19 other.

27. A process for producing a circuit board,
comprising the steps of;

disposing a first circuit member comprised of an inorganic insulating substrate, having a first connecting terminal, and a second circuit member comprised of an organic insulating substrate, having a second connecting terminal, in such a way that the first connecting terminal and the second connecting terminal face each other;

said circuit members being so disposed that the adhesive for bonding circuit members according to any one of claims 7 to 13 is put between said first connecting terminal and said second connecting terminal which have been disposed facing each other, in such a way that said third adhesive layer is on the side of said first circuit member; and

pressing the resultant circuit members to electrically interconnect said first connecting terminal and said second connecting terminal disposed facing each other.

ABSTRACT

An adhesive for bonding and securing a semiconductor chip to a circuit board and electrically connecting the electrodes of the two, and containing an adhesive resin composition and an inorganic filler being contained in
5 an amount of 10 to 200 parts by weight of 100 parts by weight of the adhesive resin composition.

09762823, 042301

1/1

FIG. 1

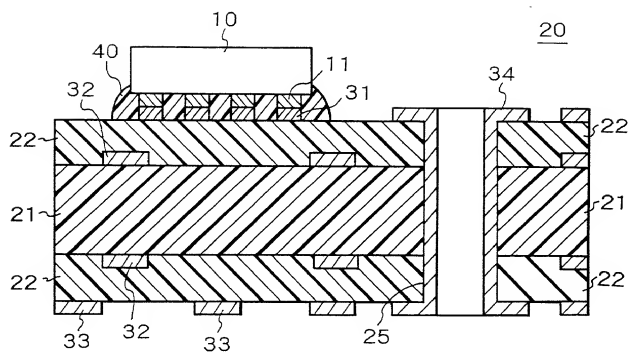
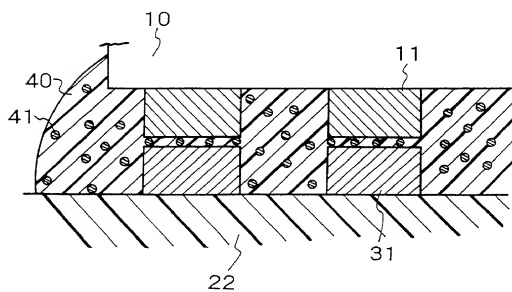


FIG. 2



CHANGE OF CORRESPONDENCE ADDRESS

Application

Address to:
 Assistant Commissioner for Patents
 Washington, D.C. 20231

Application Number	
Filing Date	FEBRUARY 13, 2001
First Named Inventor	WATANABE, ET AL.
Group Art Unit	
Examiner Name	
Attorney Docket Number	566.39636X00

Please change the Correspondence Address for the above-identified application to:

☒ Customer Number 020457
Type Customer Number here



020457

PATENT TRADEMARK OFFICE

OR

☐ Firm or
Individual Name

Address

Address

City

State

ZIP

Country

Telephone

Fax

This form cannot be used to change the data associated with a Customer Number. To change the data associated with an existing Customer Number use "Request for Customer Number Data Change" (PTO/SB/124).

I am the :

☐

Applicant.

☐

Assignee of record of the entire interest.
 Certificate under 37 CFR 3.73(b) is enclosed.

☒

Attorney or agent of record .

Typed or
Printed Name

WILLIAM I. SOLOMON

Registration NO. 28,565

Signature

William I. Solomon

Date

FEBRUARY 13, 2001.

Declaration and Power of Attorney for Patent Application

特許出願宣言書及び委任状

Japanese Language Declaration

日本語宣言書

下記の氏名の発明者として、私は以下の通り宣言します。

As a below named inventor, I hereby declare that:

私の住所、私書箱、国籍は下記の私の氏名の後に記載された通りです。

My residence, post office address and citizenship are as stated next to my name.

下記の名称の発明に関して請求範囲に記載され、特許出願している発明内容について、私が最初かつ唯一の発明者（下記の氏名が一つの場合）もしくは最初かつ共同発明者であると（下記の名称が複数の場合）信じています。

I believe I am the original, first and sole inventor (if only one name is listed below) or an original, first and joint inventor (if plural names are listed below) of the subject matter which is claimed and for which a patent is sought on the invention entitled

ADHESIVE FOR BONDING CIRCUIT
MEMBERS, CIRCUIT BOARD AND PROCESS
FOR ITS PRODUCTION

上記発明の明細書（下記の欄で印がついていない場合は、本書に添付）は、

the specification of which is attached hereto unless the following box is checked:

☐ 年 月 日に提出され、米国出願番号または特許協定条約国際出願番号を _____ とし、
（該当する場合） _____ に訂正されました。

☒ was filed on August 13, 1998
as United States Application Number or PCT
International Application Number
PCT/JP98/03609 and was amended on
_____ (if applicable)

私は、特許請求範囲を含む上記訂正後の明細書を検討し、内容を理解していることをここに表明します。

I hereby state that I have reviewed and understand the contents of the above identified specification, including the claims, as amended by any amendment referred to above.

私は、連邦規則法典第37編第1条56項に定義されるとおり、特許資格の有無について重要な情報を開示する義務があることを認めます。

I acknowledge the duty to disclose information which is material to patentability as defined in Title 37, Code of Federal Regulations, § 1.56.

Japanese Language Declaration

日本語宣言書

私は、米国法典第35編119条(a)-(d)項又は365条(b)項に基づき、下記の、米国以外の国の少なくとも一カ国を指定している特許協力条約365(a)項に基づく国際出願、又は外国での特許出願もしくは発明者証の出願についての外国優先権をここに主張するとともに、優先権を主張している本出願の前に出願された特許又は発明者証の外国出願を、以下に、枠内をマーカーすることで、示しています。

I hereby claim foreign priority under Title 35, United States Code, § 119(a)-(d) or § 365 (b) of any foreign application(s) for patent or inventor's certificate, or § 365(a) of any PCT International application which designated at least one country other than the United States, listed below and have also identified below, by checking the box, any foreign application for patent or inventor's certificate, or PCT International application having a filing date before that of the application on which priority is claimed.

Prior foreign application(s)
外国での先行出願

Priority Not Claimed
優先権主張なし

9-30983 Japan
(Number) (Country)
(番号) (国名)

14/February/1997 ☒
(Day/Month/Year Filed)
(出願年月日)

9-32003 Japan
(Number) (Country)
(番号) (国名)

17/February/1997 ☒
(Day/Month/Year Filed)
(出願年月日)

9-32004 Japan
(Number) (Country)
(番号) (国名)

17/February/1997 ☒
(Day/Month/Year Filed)
(出願年月日)

私は第35編米国法典119条(e)項に基づいて、下記の米国特許出願規定に記載された権利をここに主張いたします。

I hereby claim the benefit under Title 35, United States Code, § 119(e) of any United States provisional application(s) listed below.

(Application No.) (Filing Date)
(出願番号) (出願日)

(Application No.) (Filing Date)
(出願番号) (出願日)

私は、下記の米国法典第35編第120条に基づいて、下記の米国特許出願に記載された権利、又は米国を指定している特許協力条約第365条(c)に基づく権利をここに主張します。また、本出願の各請求範囲の内容が米国法典第35編第112条第1項又は特許協力条約で規定された方法で先行する米国特許出願に開示されていない限り、その先行米国出願書提出日以降で本出願書の日本国内又は特許協力条約国際出願提出日までの期間中に入手された、連邦規則法典第37編第1条第56項で定義された特許資格の有無に関する重要な情報について開示義務があることを認識しています。

I hereby claim the benefit under Title 35, United States Code, § 120 of any United States application(s), or § 365(c) of any PCT International application designating the United States, listed below and, insofar as the subject matter of each of the claims of this application is not disclosed in the prior United States or PCT International application in the manner provided by the first paragraph of Title 35, United States Code, § 112, I acknowledge the duty to disclose information which is material to patentability as defined in Title 37, Code of Federal Regulations, § 1.56 which became available between the filing date of the prior application and the national or PCT International filing date of this application.

(Application No.) (Filing Date)
(出願番号) (出願日)

(Status)(patented, pending, abandoned)
(現況：特許許可済、係属中、放棄済)

(Application No.) (Filing Date)
(出願番号) (出願日)

(Status)(patented, pending, abandoned)
(現況：特許許可済、係属中、放棄済)

私は、私自身の知識に基づいて本宣言書中で私が行う表明が真実であり、かつ私の入手した情報と私の信ずるところに基づく表明がすべて真実であると信じていること、さらに故意になされた虚偽の表明及びそれと同等の行為は米国法典第18編第1001条に基づき、罰金または拘禁、もしくはその両方により処罰されることを、そしてそのような故意による虚偽の声明を行えば、出願した、又は既に許可された特許の有効性が失われることを認識し、よってここに上記のごとく宣誓を致します。

I hereby declare that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under Section 1001 of Title 18 of the United States Code and that such willful false statements may jeopardize the validity of the application or any patent issued thereon.

Japanese Language Declaration

日本語宣言書

委任状： 私は、下記の発明者として、本出願に関する一切の手続を米国特許商標局に対して遂行する弁理士又は代理人として、下記のことを指名致します。(弁理士、又は代理人の氏名及び登録番号を明記のこと)

POWER OF ATTORNEY: As a named inventor, I hereby appoint the following attorney(s) and/or agent(s) to prosecute this application and transact all business in the Patent and Trademark Office connected therewith: (list name and registration number)

Donald R. Antonelli, Reg. No. 20,296; David T. Terry, Reg. No. 20,178; Melvin Kraus, Reg. No. 22,466; William I. Solomon, Reg. No. 28,565; Gregory E. Montone, Reg. No. 28,141; Ronald J. Shore, Reg. No. 28,577; Donald E. Stout, Reg. No. 26,422; Alan E. Schiavelli, Reg. No. 32,087; James N. Dresser, Reg. No. 22,973 and Carl I. Brundidge, Reg. No. 29,621

書類送付先：

Send Correspondence to:

Antonelli, Terry, Stout & Kraus, LLP
Suite 1800
1300 North Seventeenth Street
Arlington, Virginia 22209

直通電話連絡先：(名称及び電話番号)

Direct Telephone Calls to:

Telephone: (703) 312-6600
Fax: (703) 312-6666

唯一又は第一発明者名

Full name of sole or first inventor

1 - 00

Itsuo WATANABE

発明者の署名

日付

Inventor's signature

Date

Itsuo Watanabe

Apr. 15, 2001

住所

Residence

Shimodate, Japan JPX

国籍

Citizenship

Japan

郵便の宛先

Post Office Address

1194-6, Ipponmatsu, Shimodate-shi, Ibaraki-ken, 308-0842 Japan

第二共同発明者名(該当する場合)

Full name of second joint inventor, if any

2 - 00

Kenzo TAKEMURA

第二発明者の署名

日付

Second inventor's signature

Date

Kenzo Takemura

4/April/2001

住所

Residence

Yuki, Japan JPX

国籍

Citizenship

Japan

郵便の宛先

Post Office Address

8237-1, Yuki, Yuki-shi, Ibaraki-ken, 307-0001 Japan

(第三以降の共同発明者についても同様に記載し、署名をすること。)

(Supply similar information and signature for third and subsequent joint inventors.)

Japanese Language Declaration

日本語宣言書

第三共同発明者名 (該当する場合) 3-00		Full name of third joint inventor, if any <u>Akira NAGAI</u>
第三発明者の署名	日付	Third inventor's signature <u>Akira Nagai</u> 4/April/2001
住所		Residence <u>Tsukuba, Japan JPX</u>
国籍		Citizenship <u>Japan</u>
郵便の宛先		Post office address B306 Hitachi Kasei Matsushiro-House, 3-4-1, Matsushiro, Tsukuba-shi, Ibaraki-ken 305-0035 Japan
第四共同発明者名 (該当する場合) 4-00		Full name of fourth joint inventor, if any <u>Kazuhiro ISAKA</u>
第四発明者の署名	日付	Fourth inventor's signature <u>Kazuhiro Isaka</u> 9/April/2001
住所		Residence <u>Tsukuba, Japan JPX</u>
国籍		Citizenship <u>Japan</u>
郵便の宛先		Post office address Shihoryo, 1-15-18, Hanabatake, Tsukuba-shi, Ibaraki-ken 300-3261 Japan
第五共同発明者名 (該当する場合) 5-00		Full name of fifth joint inventor, if any <u>Osamu WATANABE</u>
第五発明者の署名	日付	Fifth inventor's signature <u>Osamu Watanabe</u> 5/April/2001
住所		Residence <u>Tsukuba, Japan JPX</u>
国籍		Citizenship <u>Japan</u>
郵便の宛先		Post office address Shihoryo, 1-15-18, Hanabatake, Tsukuba-shi, Ibaraki-ken 300-3261 Japan
第六共同発明者名 (該当する場合) 6-00		Full name of sixth joint inventor, if any <u>Kazuyoshi KOJIMA</u>
第六発明者の署名	日付	Sixth inventor's signature <u>Kazuyoshi Kojima</u> 5/April/2001
住所		Residence <u>Tsukuba, Japan JPX</u>
国籍		Citizenship <u>Japan</u>
郵便の宛先		Post office address Shihoryo, 1-15-18, Hanabatake, Tsukuba-shi, Ibaraki-ken 300-3261 Japan

日本語宣言書

Additional prior foreign applications:

[illegible]

Application Number (出願番号)	Filing Date (出願日)
•	
•	

Application Number (出願番号)	Filing Date (出願日)	Status (patented, pending, abandoned) (現況：特許許可済、係属中、放棄済)

[illegible]